	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	51	("6154285") or ("6195448")	EPO;	2004/08/26 11:45
2	BRS	L2	0	1 and transparent near3 insulat\$3 adj layer	USPAT; EPO; JPO; USOCR	2004/08/26 11:53
3	BRS	L3	0	1 and transparent near3 insulat\$3 adj layer	USPAT; EPO; JPO; USOCR	2004/08/26 11:46
4	BRS	L4	2	1 and transparent near3 insulat\$3 and material	USPAT; EPO; JPO; USOCR	2004/08/26 11:47
5	BRS	L5	1	4 and conduct\$3 near3 material	USPAT; EPO; JPO; USOCR	2004/08/26 11:56

	Туре	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	0	5 and polyer near3 paste		2004/08/26 11:56
7	BRS	L7	0	5 and dielectric and polyer	USPAT; EPO; JPO; USOCR	2004/08/26 11:48
8	BRS	L8	0	1 and dielectric and polyer	USPAT; EPO; JPO; USOCR	2004/08/26 11:48
9	BRS	L9	4	fabricat\$3 near3(fingerprint or finger adj print)with device	USPAT; EPO; JPO; USOCR	2004/08/26 11:54
10	BRS	L10	1919	transparent near3 insulat\$3 adj layer	I	2004/08/26 12:01
11	BRS .	L11	0	10 and fabricat\$3 near3(fingerprint or finger adj print)and device	USPAT; EPO; JPO; USOCR	2004/08/26 11:55
12	BRS	L12	153	10 and fabricat\$3 near3 device	:	2004/08/26 11:54
13	BRS	L13	0	12 and(fingerprint or finger adj print)	:	2004/08/26 11:55
14	BRS	L14	8	12 and recogniz\$3 near3 device	:	2004/08/26 11:55
15	BRS	L15	5	14 and conduct\$3 near3 material	:	2004/08/26 11:56

	Туре	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L16	0	15 and polyer near3 paste		2004/08/26 11:57
17	BRS	L17	0	10 and polyer near3 paste	USPAT; EPO; JPO; USOCR	2004/08/26 11:57
18	BRS	L18	0	polyer near3 paste	USPAT; EPO; JPO; USOCR	2004/08/26 12:02
19	BRS	L19	2	dielectric near3 polyer	USPAT; EPO; JPO; USOCR	2004/08/26 12:02
20	BRS	L20	0	10 and 19		2004/08/26 11:58
21	BRS	L21	0	19 and paste	USPAT; EPO; JPO; USOCR	2004/08/26 11:58
22	BRS	L22	0	19 and retarder	USPAT; EPO; JPO; USOCR	2004/08/26 12:12
23	BRS	L23	0	19 and (dopant adj doped or dopant-doped)		2004/08/26 12:00
24	BRS	L24	949	(dopant adj doped or dopant-doped)		2004/08/26 12:12
25	BRS	L25	0	24 and polyer near3 paste		2004/08/26 12:00

	Туре	L #	Hits	Search Text	DBs	Time Stamp
26	BRS	L26	0	polyer	•	2004/08/26 12:00
27	BRS	L27	2	24 and transparent near3 insulat\$3 adj layer		2004/08/26 12:01
28	BRS	L28	0	27 and polyer near3 paste		2004/08/26 12:10
29	BRS	L29	1			2004/08/26 12:10
30	BRS	T30	0	20 and polyon	1	2004/08/26 12:02
31	BRS	L32	0	31 and percentage	•	2004/08/26 12:13
32	BRS	L31	1	29 and paste		2004/08/26 12:03
33	BRS	L33	423	24 and dielectric		2004/08/26 12:10
34	BRS	L34	0	33 and polyer near3 paste	USPAT; EPO; JPO; USOCR	2004/08/26 12:21
35	BRS	L35	13	33 and paste	:	2004/08/26 12:11

	Туре	L #	Hits	Search Text	DBs	Time Stamp
36	BRS	L36	13	35 and(dopant adj doped or dopant-doped)	USPAT; EPO; JPO; USOCR	2004/08/26 12:12
37	BRS	L37	0	19 and retarder	USPAT; EPO; JPO; USOCR	2004/08/26 12:13
38	BRS	L38	2	36 and percentage	USPAT; EPO; JPO; USOCR	2004/08/26 12:13
39	BRS	L39	1	38 and @ad<20001107	USPAT; EPO; JPO; USOCR	2004/08/26 12:14
40	BRS	L40	0	39 and polyer adj1 paste	USPAT; EPO; JPO; USOCR	: :
41	BRS	L41	0	39 and polyer	USPAT; EPO; JPO; USOCR	2004/08/26 12:21